

DATA SHEET

For a complete data sheet, please also download:

- The IC06 74HC/HCT/HCU/HCMOS Logic Family Specifications
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Information
- The IC06 74HC/HCT/HCU/HCMOS Logic Package Outlines

74HC/HCT4316 Quad bilateral switches

Product specification
File under Integrated Circuits, IC06

September 1993

Quad bilateral switches

74HC/HCT4316

FEATURES

- Low “ON” resistance:
160 Ω (typ.) at $V_{CC} - V_{EE} = 4.5$ V
120 Ω (typ.) at $V_{CC} - V_{EE} = 6.0$ V
80 Ω (typ.) at $V_{CC} - V_{EE} = 9.0$ V
- Logic level translation:
to enable 5 V logic to communicate
with ± 5 V analog signals
- Typical “break before make” built in
- Output capability: non-standard
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT4316 are high-speed Si-gate CMOS devices. They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT4316 have four independent analog switches. Each switch has two input/output terminals (nY, nZ) and an active HIGH select input (nS). When the enable input ($\bar{E}$) is HIGH, all four analog switches are turned off.

Current through a switch will not cause additional V_{CC} current provided the voltage at the terminals of the switch is maintained within the supply voltage range; $V_{CC} \gg (V_Y, V_Z) \gg V_{EE}$. Inputs nY and nZ are electrically equivalent terminals.

V_{CC} and GND are the supply voltage pins for the digital control inputs ($\bar{E}$ and nS). The V_{CC} to GND ranges are 2.0 to 10.0 V for HC and 4.5 to 5.5 V for HCT.

The analog inputs/outputs (nY and nZ) can swing between V_{CC} as a positive limit and V_{EE} as a negative limit.

$V_{CC} - V_{EE}$ may not exceed 10.0 V.

See the “4016” for the version without logic level translation.

QUICK REFERENCE DATA

$V_{EE} = \text{GND} = 0$ V; $T_{\text{amb}} = 25$ °C; $t_r = t_f = 6$ ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t _{PZH}	turn “ON” time E̅ to V _{OS} nS to V _{OS}	C _L = 15 pF; R _L = 1 kΩ; V _{CC} = 5 V	19	19	ns
			16	17	ns
t _{PZL}	turn “ON” time E̅ to V _{OS} nS to V _{OS}		19	24	ns
			16	21	ns
t _{PHZ} / t _{PLZ}	turn “OFF” time E̅ to V _{OS} nS to V _{OS}		20	21	ns
			16	19	ns
C _I	input capacitance			3.5	3.5
C _{PD}	power dissipation capacitance per switch	notes 1 and 2	13	14	pF
C _S	max. switch capacitance		5	5	pF

Notes

- C_{PD} is used to determine the dynamic power dissipation (P_D in μ W):

$$P_D = C_{PD} \times V_{CC}^2 \times f_i + \sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$$
 where:
 f_i = input frequency in MHz
 f_o = output frequency in MHz
 $\sum \{ (C_L + C_S) \times V_{CC}^2 \times f_o \}$ = sum of outputs

C_L = output load capacitance in pF

C_S = max. switch capacitance in pF

V_{CC} = supply voltage in V

- For HC the condition is $V_I = \text{GND}$ to V_{CC}
For HCT the condition is $V_I = \text{GND}$ to $V_{CC} - 1.5$ V

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ORDERING INFORMATION

See *“74HC/HCT/HCU/HCMOS Logic Package Information”*.

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 4, 10, 13	1Z to 4Z	independent inputs/outputs
2, 3, 11, 12	1Y to 4Y	independent inputs/outputs
7	$\overline{E}$	enable input (active LOW)
8	GND	ground (0 V)
9	V_{EE}	negative supply voltage
15, 5, 6, 14	1S to 4S	select inputs (active HIGH)
16	V_{CC}	positive supply voltage



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FUNCTION TABLE

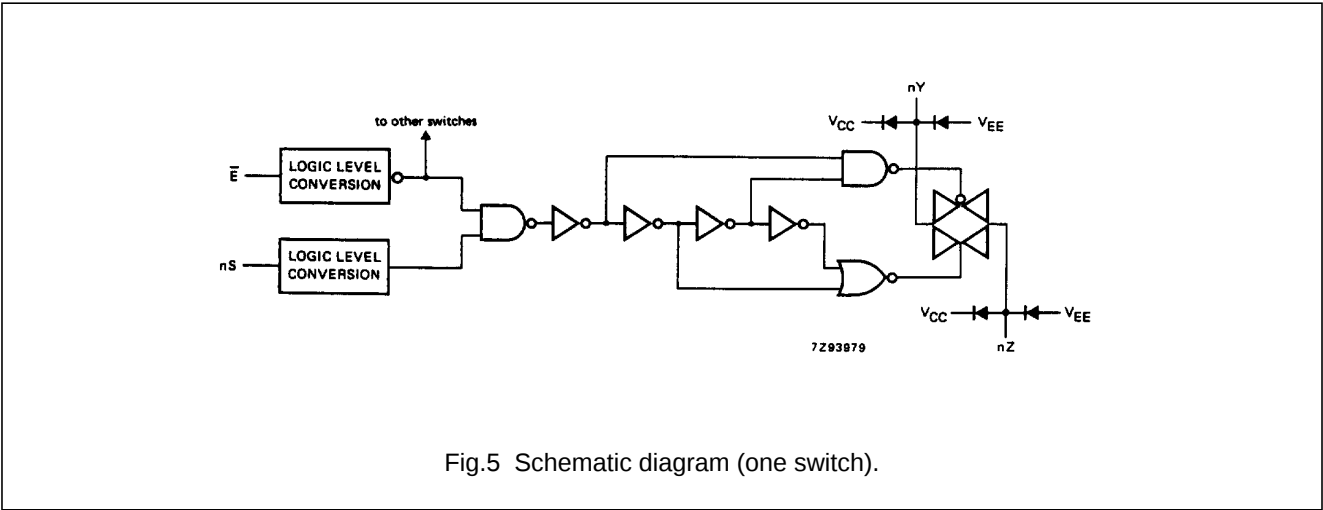
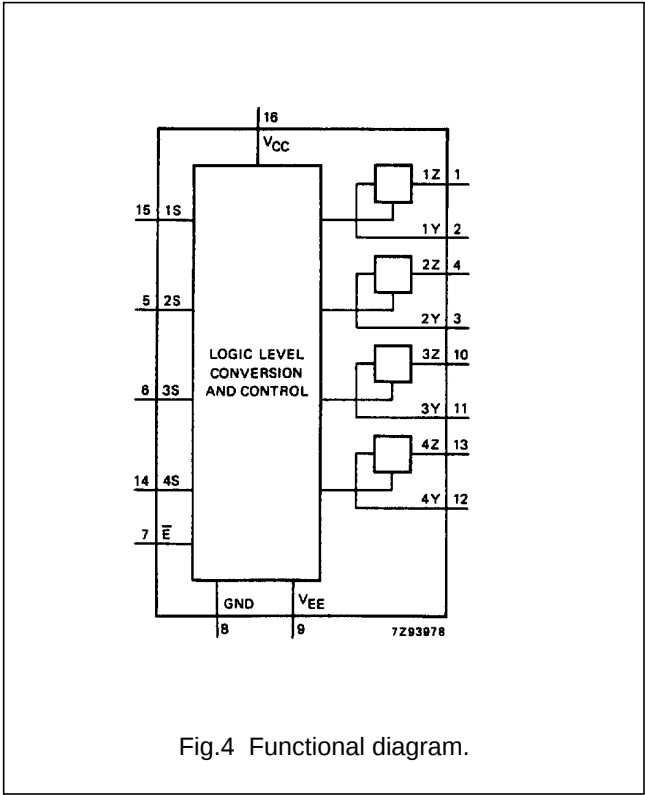
INPUTS		SWITCH
$\overline{E}$	nS	
L	L	off
L	H	on
H	X	off

Note

1. H = HIGH voltage level
- L = LOW voltage level
- X = don't care

APPLICATIONS

- Signal gating
- Modulation
- Demodulation
- Chopper



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RATINGS

Limiting values in accordance with the Absolute Maximum System (IEC 134)

Voltages are referenced to $V_{EE} = \text{GND}$ (ground = 0 V)

SYMBOL	PARAMETER	MIN.	MAX.	UNIT	CONDITIONS
V_{CC}	DC supply voltage	-0.5	+11.0	V	
$\pm I_{IK}$	DC digital input diode current		20	mA	for $V_I < -0.5 \text{ V}$ or $V_I > V_{CC} + 0.5 \text{ V}$
$\pm I_{SK}$	DC switch diode current		20	mA	for $V_S < -0.5 \text{ V}$ or $V_S > V_{CC} + 0.5 \text{ V}$
$\pm I_S$	DC switch current		25	mA	for $-0.5 \text{ V} < V_S < V_{CC} + 0.5 \text{ V}$
$\pm I_{EE}$	DC V_{EE} current		20	mA	
$\pm I_{CC}$; $\pm I_{GND}$	DC V_{CC} or GND current		50	mA	
T_{stg}	storage temperature range	-65	+150	°C	
P_{tot}	power dissipation per package				for temperature range: -40 to +125 °C 74HC/HCT
	plastic DIL		750	mW	above +70 °C: derate linearly with 12 mW/K
	plastic mini-pack (SO)		500	mW	above +70 °C: derate linearly with 8 mW/K
P_S	power dissipation per switch		100	mW	

Note to ratings

To avoid drawing V_{CC} current out of terminal Z, when switch current flows in terminals Y_n , the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminals Z, no V_{CC} current will flow out of terminal Y_n . In this case there is no limit for the voltage drop across the switch, but the voltages at Y_n and Z may not exceed V_{CC} or V_{EE} .

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	74HC			74HCT			UNIT	CONDITIONS
		min.	typ.	max.	min.	typ.	max.		
V_{CC}	DC supply voltage V_{CC} -GND	2.0	5.0	10.0	4.5	5.0	5.5	V	see Figs 6 and 7
V_{CC}	DC supply voltage V_{CC} - V_{EE}	2.0	5.0	10.0	2.0	5.0	10.0	V	see Figs 6 and 7
V_I	DC input voltage range	GND		V_{CC}	GND		V_{CC}	V	
V_S	DC switch voltage range	V_{EE}		V_{CC}	V_{EE}		V_{CC}	V	
T_{amb}	operating ambient temperature range	-40		+85	-40		+85	°C	see DC and AC CHARACTERISTICS
T_{amb}	operating ambient temperature range	-40		+125	-40		+125	°C	
t_r, t_f	input rise and fall times		6.0	1000 500 400 250		6.0	500	ns	$V_{CC} = 2.0 \text{ V}$ $V_{CC} = 4.5 \text{ V}$ $V_{CC} = 6.0 \text{ V}$ $V_{CC} = 10.0 \text{ V}$

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Fig.6 Guaranteed operating area as a function of the supply voltages for 74HC4316.



Fig.7 Guaranteed operating area as a function of the supply voltages for 74HCT4316.

DC CHARACTERISTICS FOR 74HC/HCT

For 74HC: $V_{CC} - GND$ or $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$ and 9.0 V

For 74HCT: $V_{CC} - GND = 4.5$ and 5.5 V; $V_{CC} - V_{EE} = 2.0, 4.5, 6.0$ and 9.0 V

SYMBOL	PARAMETER	T _{amb} (°C)							UNIT	TEST CONDITIONS				
		74HC/HCT								V _{CC} (V)	V _{EE} (V)	I _S (μA)	V _{is}	V _I
		+25			−40 to +85		−40 to +125							
		min.	typ.	max.	min.	max.	min.	max.						
R _{ON}	ON resistance (peak)		—	—		—		—	Ω	2.0	0	100	V _{CC} to V _{EE}	V _{IH} or V _{IL}
			160	320		400		480	Ω	4.5	0	1000		
			120	240		300		360	Ω	6.0	0	1000		
			85	170		215		255	Ω	4.5	−4.5	1000		
R _{ON}	ON resistance (rail)		160	—		—		—	Ω	2.0	0	100	V _{EE}	V _{IH} or V _{IL}
			80	160		200		240	Ω	4.5	0	1000		
			70	140		175		210	Ω	6.0	0	1000		
			60	120		150		180	Ω	4.5	−4.5	1000		
R _{ON}	ON resistance (rail)		170	—		—		—	Ω	2.0	0	100	V _{CC}	V _{IH} or V _{IL}
			90	180		225		270	Ω	4.5	0	1000		
			80	160		200		240	Ω	6.0	0	1000		
			65	135		170		205	Ω	4.5	−4.5	1000		
ΔR _{ON}	maximum ΔON resistance between any two channels		—						Ω	2.0	0		V _{CC} to V _{EE}	V _H or V _{IL}
			16						Ω	4.5	0			
			9						Ω	6.0	0			
			6						Ω	4.5	−4.5			

Notes

- At supply voltages ($V_{CC} - V_{EE}$) approaching 2.0 V the analog switch ON-resistance becomes extremely non-linear. Therefore it is recommended that these devices are used to transmit digital signals only, when using these supply voltages.
- For test circuit measuring R_{ON} see Fig.8.

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DC CHARACTERISTICS FOR 74HC

Voltages are referenced to GND (ground = 0 V)

SYMBOL	PARAMETER	T _{amb} (°C)							UNIT	TEST CONDITIONS			
		74HC								V _{CC} (V)	V _{EE} (V)	V _I	OTHER
		+25			−40 to +85		−40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
V _{IH}	HIGH level input voltage	1.5 3.15 4.2 6.3	1.2 2.4 3.2 4.3		1.5 3.15 4.2 6.3		1.5 3.15 4.2 6.3		V	2.0 4.5 6.0 9.0			
V _{IL}	LOW level input voltage		0.8 2.1 2.8 4.3	0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7		0.5 1.35 1.8 2.7	V	2.0 4.5 6.0 9.0			
±I _I	input leakage current			0.1 0.2		1.0 2.0		1.0 2.0	μA	6.0 10.0	0 0	V _{CC} or GND	
±I _S	analog switch OFF-state current			0.1		1.0		1.0	μA	10.0	0	V _{IH} or V _{IL}	V _S = V _{CC} − V _{EE} (see Fig.10)
±I _S	analog switch ON-state current			0.1		1.0		1.0	μA	10.0	0	V _{IH} or V _{IL}	V _S = V _{CC} − V _{EE} (see Fig.11)
I _{CC}	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	6.0 10.0	0 0	V _{CC} or GND	V _{is} = V _{EE} or V _{CC} ; V _{OS} = V _{CC} or V _{EE}

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AC CHARACTERISTICS FOR 74HC

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T _{amb} (°C)								UNIT	TEST CONDITIONS		
		74HC									V _{CC} (V)	V _{EE} (V)	OTHER
		+25			−40 to +85		−40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
t _{PHL} / t _{PLH}	propagation delay V _{is} to V _{os}		17	60		75		90	ns	2.0	0	R _L = ∞; C _L = 50 pF (see Fig.18)	
			6	12		15		18		4.5	0		
			5	10		13		15		6.0	0		
			4	8		10		12		4.5	−4.5		
t _{PZH} / t _{PZL}	turn “ON” time E̅ to V _{os}		61	205		255		310	ns	2.0	0	R _L = 1 kΩ; C _L = 50 pF (see Figs 19, 20 and 21)	
			22	41		51		62		4.5	0		
			18	35		43		53		6.0	0		
			19	37		47		56		4.5	−4.5		
t _{PZH} / t _{PZL}	turn “ON” time nS to V _{os}		52	175		220		265	ns	2.0	0	R _L = 1 kΩ; C _L = 50 pF (see Figs 19, 20 and 21)	
			19	35		44		53		4.5	0		
			15	30		37		45		6.0	0		
			17	34		43		51		4.5	−4.5		
t _{PHZ} / t _{PLZ}	turn “OFF” time E̅ to V _{os}		63	220		275		330	ns	2.0	0	R _L = 1 kΩ; C _L = 50 pF (see Figs 19, 20 and 21)	
			23	44		55		66		4.5	0		
			18	37		47		56		6.0	0		
			21	39		49		59		4.5	−4.5		
t _{PHZ} / t _{PLZ}	turn “OFF” time nS to V _{os}		55	175		220		265	ns	2.0	0	R _L = 1 kΩ; C _L = 50 pF (see Figs 19, 20 and 21)	
			20	35		44		53		4.5	0		
			16	30		37		45		6.0	0		
			18	36		45		54		4.5	−4.5		

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DC CHARACTERISTICS FOR 74HCT

Voltages are referenced to GND (ground = 0)

SYMBOL	PARAMETER	T _{amb} (°C)							UNIT	TEST CONDITIONS			
		74HCT								V _{CC} (V)	V _{EE} (V)	V _I	OTHER
		+25			−40 to +85		−40 to +125						
		min.	typ.	max.	min.	max.	min.	max.					
V _{IH}	HIGH level input voltage	2.0	1.6		2.0		2.0		V	4.5 to 5.5			
V _{IL}	LOW level input voltage		1.2	0.8		0.8		0.8	V	4.5 to 5.5			
±I _I	input leakage current			0.1		1.0		1.0	μA	5.5	0	V _{CC} or GND	
±I _S	analog switch OFF-state current			0.1		1.0		1.0	μA	10.0	0	V _{IH} or V _{IL}	M _S = V _{CC} − V _{EE} (see Fig.10)
±I _S	analog switch ON-state current			0.1		1.0		1.0	μA	10.0	0	V _{IH} or V _{IL}	M _S = V _{CC} − V _{EE} (see Fig.11)
I _{CC}	quiescent supply current			8.0 16.0		80.0 160.0		160.0 320.0	μA	5.5 5.0	0 −5.0	V _{CC} or GND	V _{IS} = V _{EE} or V _{CC} ; V _{OS} = V _{CC} or V _{EE}
ΔI _{CC}	additional quiescent supply current per input pin for unit load coefficient is 1 (note 1)		100	360		450		490	μA	4.5 to 5.5	0	V _{CC} −2.1 V	other inputs at V _{CC} or GND

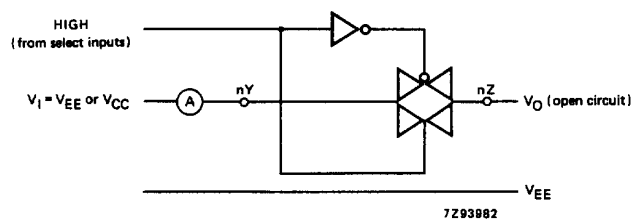
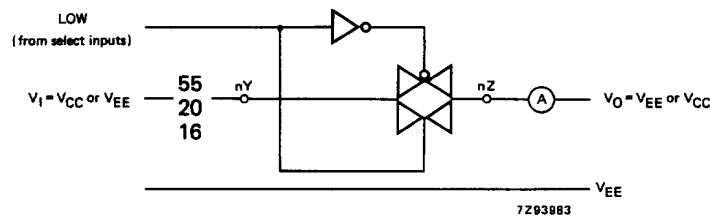
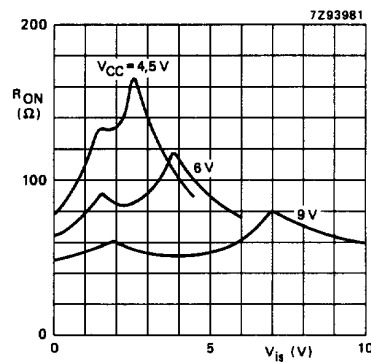
Note

1. The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given here.
To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
nS	0.50
$\bar{E}$	0.50

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AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T _{amb} (°C)							UNIT	TEST CONDITIONS		
		74HCT								V _{CC} (V)	V _{EE} (V)	OTHER
		+25			−40 TO +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t _{PHL} / t _{PLH}	propagation delay V _{IS} to V _{OS}		6 4	12 8		15 10		18 12	ns	4.5 4.5	0 −4.5	R _L = ∞; C _L = 50 pF (see Fig.18)
t _{PZH}	turn “ON” time E̅ to V _{OS}		22 21	44 42		55 53		66 63	ns	4.5 4.5	0 −4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 19, 20 and 21)
t _{PZL}	turn “ON” time E̅ to V _{OS}		28 21	56 42		70 53		84 63	ns	4.5 4.5	0 −4.5	
t _{PZH}	turn “ON” time nS to V _{OS}		20 17	40 34		53 43		60 51	ns	4.5 4.5	0 −4.5	
t _{PZL}	turn “ON” time nS to V _{OS}		25 17	50 34		63 43		75 51	ns	4.5 4.5	0 −4.5	(see Figs 19, 20 and 21)
t _{PHZ} / t _{PLZ}	turn “OFF” time E̅ to V _{OS}		25 23	50 46		63 58		75 69	ns	4.5 4.5	0 −4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 19, 20 and 21)
t _{PHZ} / t _{PLZ}	turn “OFF” time nS to V _{OS}		22 20	44 40		55 50		66 60	ns	4.5 4.5	0 −4.5	R _L = 1 kΩ; C _L = 50 pF (see Figs 19, 20 and 21)

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ADDITIONAL AC CHARACTERISTICS FOR 74HC/HCT

Recommended conditions and typical values

GND = 0 V; $T_{amb} = 25\text{ }^{\circ}\text{C}$

SYMBOL	PARAMETER	typ.	UNIT	V_{CC} (V)	V_{EE} (V)	$V_{is(p-p)}$ (V)	CONDITIONS
	sine-wave distortion $f = 1\text{ kHz}$	0.80 0.40	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	$R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$ (see Fig.14)
	sine-wave distortion $f = 10\text{ kHz}$	2.40 1.20	% %	2.25 4.5	-2.25 -4.5	4.0 8.0	$R_L = 10\text{ k}\Omega$; $C_L = 50\text{ pF}$ (see Fig.14)
	switch "OFF" signal feed-through	-50 -50	dB dB	2.25 4.5	-2.25 -4.5	note 1	$R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$ $f = 1\text{ MHz}$ (see Figs 12 and 15)
	crosstalk between any two switches	-60 -60	dB dB	2.25 4.5	-2.25 -4.5	note 1	$R_L = 600\text{ }\Omega$; $C_L = 50\text{ pF}$; $f = 1\text{ MHz}$; (see Fig.16)
$V_{(p-p)}$	crosstalk voltage between control and any switch (peak-to-peak value)	110 220	mV mV	4.5 4.5	0 -4.5		$R_L = 600\text{ k}\Omega$; $C_L = 50\text{ pF}$; $f = 1\text{ MHz}$ ($\bar{E}$ or nS, square-wave between V_{CC} and GND, $t_r = t_f = 6\text{ ns}$) (see Fig.17)
f_{max}	minimum frequency response (-3 dB)	150 160	MHz MHz	2.25 4.5	-2.25 -4.5	note 2	$R_L = 50\text{ }\Omega$; $C_L = 10\text{ pF}$ (see Figs 13 and 14)
C_S	maximum switch capacitance	5	pF				

Notes

1. Adjust input voltage V_{is} to 0 dBm level (0 dBm = 1 mW into 600 Ω).
2. Adjust input voltage V_{is} to 0 dBm level at V_{OS} for 1 MHz (0 dBm = 1 mW into 50 Ω).

General note

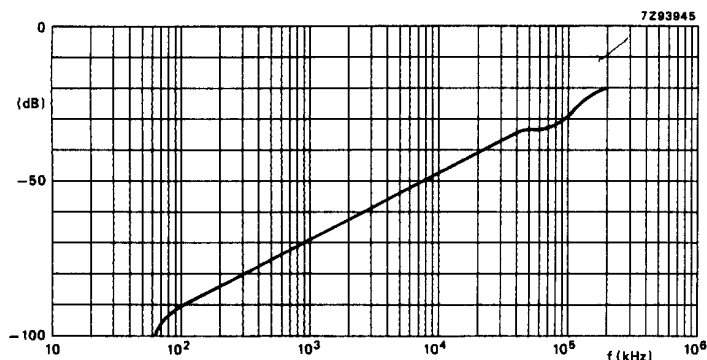
 V_{is} is the input voltage at an nY or nZ terminal, whichever is assigned as an input. V_{OS} is the output voltage at an nY or nZ terminal, whichever is assigned as an output.

Fig.12 Typical switch "OFF" signal feed-through as a function of frequency.

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Test conditions:
 $V_{CC} = 4.5\text{ V}$; $GND = 0\text{ V}$; $V_{EE} = -4.5\text{ V}$;
 $R_L = 50\ \Omega$; $R_{source} = 1\text{ k}\Omega$.



Fig.13 Typical frequency response.



Fig.14 Test circuit for measuring sine-wave distortion and minimum frequency response.



Fig.15 Test circuit for measuring switch "OFF" signal feed-through.

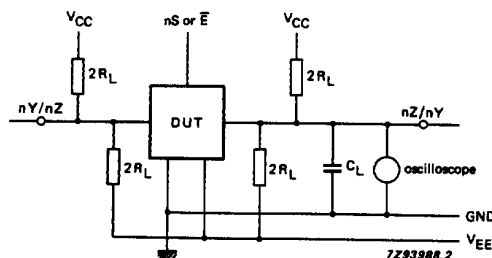
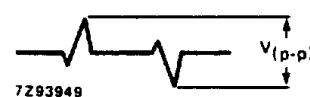
Fig.16 Test circuit for measuring crosstalk between two switches.
(a) channel ON condition; (b) channel OFF condition.

Fig.17 Test circuit for measuring crosstalk between control and any switch.

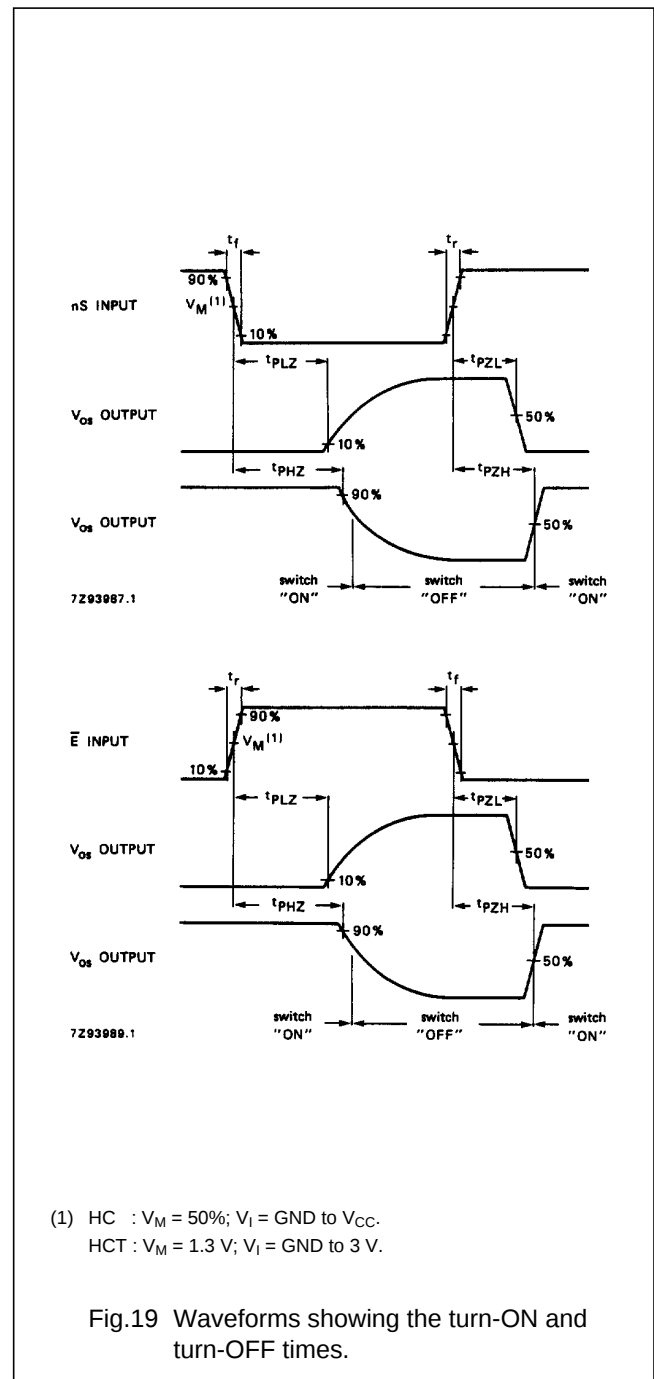
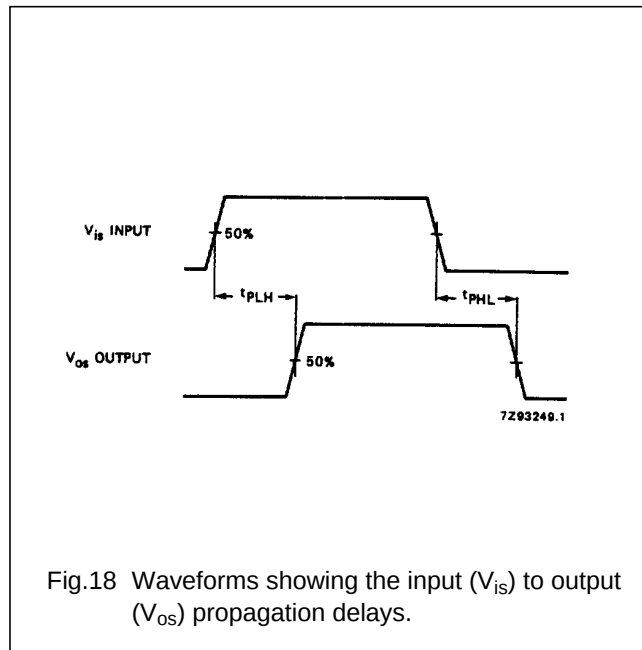
The crosstalk is defined as follows
(oscilloscope output):



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AC WAVEFORMS



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TEST CIRCUIT AND WAVEFORMS



Fig.20 Test circuit for measuring AC performance.



Fig.21 Input pulse definitions.

Conditions

TEST	SWITCH	V_{is}
t_{PZH}	V_{EE}	V_{CC}
t_{PZL}	V_{CC}	V_{EE}
t_{PHZ}	V_{EE}	V_{CC}
t_{PLZ}	V_{CC}	V_{EE}
others	open	pulse

FAMILY	AMPLITUDE	V_M	$t_r; t_f$	
			$f_{max};$ PULSE WIDTH	OTHER
74HC	V_{CC}	50%	< 2 ns	6 ns
74HCT	3.0 V	1.3 V	< 2 ns	6 ns

Definitions for Figs 20 and 21:

C_L = load capacitance including jig and probe capacitance (see AC CHARACTERISTICS for values).

R_T = termination resistance should be equal to the output impedance Z_O of the pulse generator.

$t_r = t_f = 6$ ns; when measuring f_{max} , there is no constraint to t_r, t_f with 50% duty factor.

PACKAGE OUTLINES

See "74HC/HCT/HCU/HCMOS Logic Package Outlines".



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

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